

### **Description**

The BSC097N06NS uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

 $V_{DS} = 60V I_{D} = 65A$ 

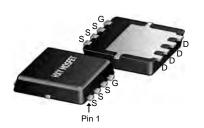
 $R_{DS(ON)} < 11 m\Omega V_{GS} = 10 V$ 

### **Application**

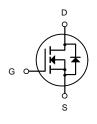
Battery protection

Load switch

Uninterruptible power supply



DFN5X6-8L



N-Channel MOSFET

### **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
BSC097N06NS	DFN5X6-8L	097N06NS	5000

Absolute Maximum Ratings (T<sub>C</sub>=25<sup>°</sup>Cunless otherwise noted)

Symbol	Parameter	Rating	Units		
Vos	Drain-Source Voltage	60	V		
Vgs	Gate-Source Voltage	±20			
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	t, V <sub>GS</sub> @ 10V 65			
I <sub>D</sub> @T <sub>C</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	Continuous Drain Current, V <sub>GS</sub> @ 10V 49			
Ідм	Pulsed Drain Current <sup>2</sup> 180		А		
EAS	Single Pulse Avalanche Energy <sup>3</sup>	y <sup>3</sup> 56			
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	89	W		
Тѕтс	Storage Temperature Range	-55 to 150	°C		
TJ	Operating Junction Temperature Range	-55 to 150	°C		
R <sub>0</sub> JA	Thermal Resistance Junction-Ambient <sup>1</sup> 62		°C/W		



# **Electrical Characteristics** (T<sub>J</sub>=25°C unless otherwise specified)

Symbol	Parameter Test Condition		Min.	Тур.	Max.	Units		
Off Characteristic								
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60	_	-	V		
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V,	-	-	1.0	μA		
I <sub>GSS</sub>	Gate to Body Leakage Current	nt V <sub>DS</sub> =0V, V <sub>GS</sub> = ±20V		-	±100	nA		
On Charac	Characteristics							
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.6	2.5	V		
0	Static Drain-Source on-Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	8	11	0		
$R_{DS(on)}$	note3	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		14	20	mΩ		
Dynamic (	Characteristics							
C <sub>iss</sub>	Input Capacitance	\\ O5\\\\\ O\\	_	930	-	pF		
Coss	Output Capacitance	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHz	_	370	-	pF		
C <sub>rss</sub>	Reverse Transfer Capacitance	1-1.0IVII 12	-	20	-	pF		
Qg	Total Gate Charge	\/=20\/	-	19	-	nC		
$Q_gs$	Gate-Source Charge	V <sub>DS</sub> =30V, I <sub>D</sub> =20A, V <sub>GS</sub> =10V	-	4.8	-	nC		
$Q_gd$	Gate-Drain("Miller") Charge	VGS-10 V	-	4.5	-	nC		
Switching	Characteristics							
t <sub>d(on)</sub>	Turn-on Delay Time		-	4.9	-	ns		
t <sub>r</sub>	Turn-on Rise Time	$V_{DD}$ =30 $V$ , $I_D$ =20 $A$ ,	-	31	-	ns		
t <sub>d(off)</sub>	Turn-off Delay Time	$R_G$ =1.6 $\Omega$ , $V_{GS}$ =10 $V$	-	23	-	ns		
t <sub>f</sub>	Turn-off Fall Time		-	8.7	-	ns		
Drain-Sou	rce Diode Characteristics and Maximu	um Ratings						
Is	Maximum Continuous Drain to Source Diode Forward Current		-	-	65	А		
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current			-	240	Α		
$V_{SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> =0V, I <sub>S</sub> =30A	-	-	1.4	V		
t <sub>rr</sub>	Body Diode Reverse Recovery Time	T -05°0	-	34	-	ns		
Qrr	Body Diode Reverse Recovery Charge	T <sub>J</sub> =25℃, I <sub>F</sub> =20A,dI/dt=100A/μs	-	14	-	nC		

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

- 2. EAS condition:  $T_J$ =25  $^{\circ}$ C,  $V_{DD}$ =30V,  $V_G$ =10V,  $R_G$ =25 $\Omega$ , L=0.5mH,  $I_{AS}$ =12A
- 3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



# **Typical Performance Characteristics**

Figure1: Output Characteristics

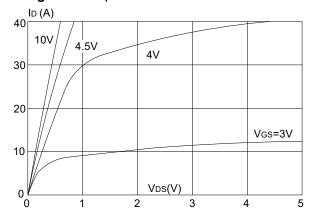


Figure 3:On-resistance vs. Drain Current

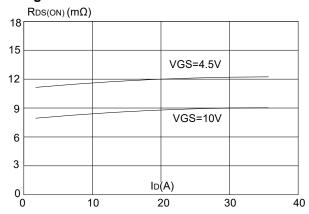


Figure 5: Gate Charge Characteristics

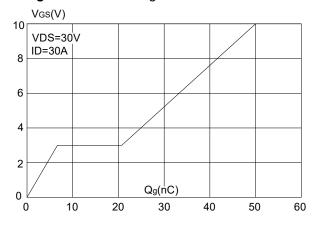


Figure 2: Typical Transfer Characteristics

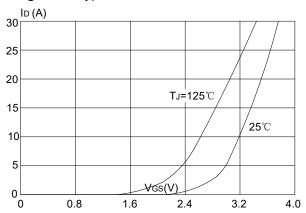


Figure 4: Body Diode Characteristics

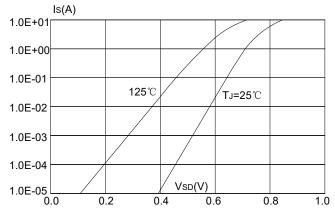
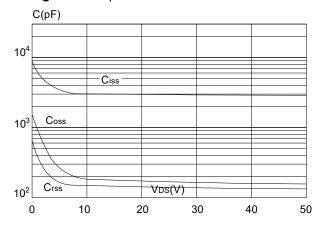


Figure 6: Capacitance Characteristics





**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature

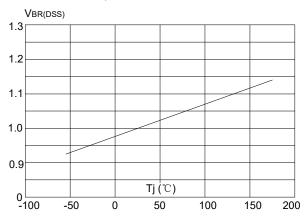
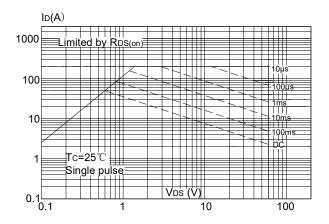
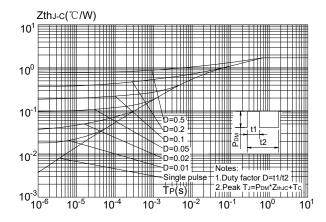


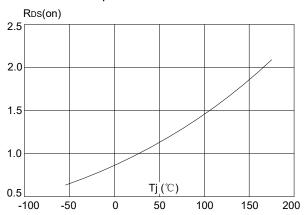
Figure 9: Maximum Safe Operating Area



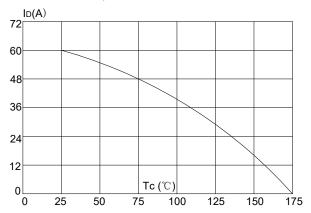
**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



**Figure 8:** Normalized on Resistance vs. Junction Temperature

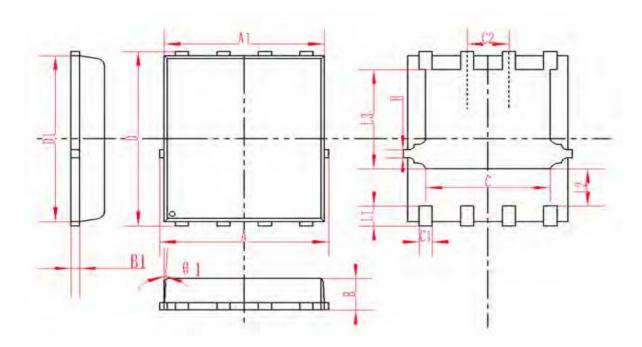


**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature





# **DFN5X6-8L Package Information**



SYMBOL	MM		INCH			
STIVIDOL	MIN	NOM	MAX	MIN	NOM	MAX
А	4.95	5	5.05	0.195	0.197	0.199
A1	4.82	4.9	4.98	0.190	0.193	0.196
D	5.98	6	6.02	0.235	0.236	0.237
D1	5.67	5.75	5.83	0.223	0.226	0.230
В	0.9	0.95	1	0.035	0.037	0.039
B1	0.254REF		0.010REF			
С	3.95	4	4.05	0.156	0.157	0.159
C1	0.35	0.4	0.45	0.014	0.016	0.018
C2		1.27TYP			0.5TYP	
θ1	8°	10°	12°	8°	10°	12°
L1	0.63	0.64	0.65	0.025	0.025	0.026
L2	1.2	1.3	1.4	0.047	0.051	0.055
L3	3.415	3.42	3.425	0.134	0.135	0.135
Н	0.24	0.25	0.26	0.009	0.010	0.010

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